

SCDS319-JUNE 2011

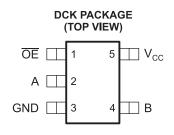
SINGLE FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER

Check for Samples: SN74CB3T1G125-Q1

FEATURES

- Qualified for Automotive Applications
- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation on All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level Shift With 2.5-V V_{CC}
- 5-V-Tolerant I/Os, With Device Powered Up or Powered Down
- Bidirectional Data Flow With Near-Zero
 Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics (r_{on} = 5 Ω Typ)
- Low Input/Output Capacitance Minimizes Loading (C_{io(OFF)} = 5 pF Typ)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I_{CC} = 20 µA Max)

- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Supports Digital Applications: Level Translation, USB Interface, Bus Isolation
- Ideal for Low-Power Portable Equipment



DESCRIPTION

The SN74CB3T1G125-Q1 is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC}. The SN74CB3T1G125-Q1 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

The SN74CB3T1G125-Q1 is a 1-bit bus switch with a single ouput-enable (\overline{OE}) input. When \overline{OE} is low, the bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

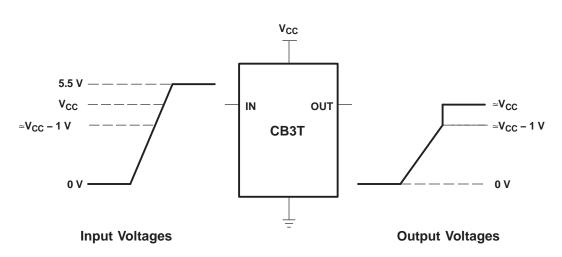


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NOTE A: If the input high voltage (V_{IH}) level is greater than or equal to $V_{CC} - 1$ V, and less than or equal to 5.5 V, then the output high voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

ORDERING INFORMATION

T _A	PACKAG	GE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING ⁽²⁾
-40°C to 125°C	SOT (SC-70) – DCK	Reel of 3000	CCB3T1G125QDCKRQ1	72_

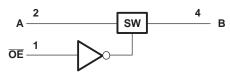
(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) The actual top-side marking has one additional character that designates the assembly/test site.

FUNCTION TABLE

INPUT OE	INPUT/OUTPUT A	FUNCTION
L	В	A port = B port
н	Z	Disconnect

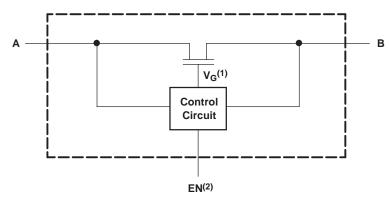
LOGIC DIAGRAM (POSITIVE LOGIC)





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SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



(1) Gate voltage (V_G) is equal to approximately $V_{CC} + V_T$ when the switch is ON and $V_I > V_{CC} + V_T$. (2) EN is the internal enable signal applied to the switch.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
V _{IN}	Control input voltage range ^{(2) (3)}		–0.5 7 V		
V _{I/O}	Switch I/O voltage range ^{(2) (3) (4)}		-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0		-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0		-50	mA
I _{IO}	ON-state switch current ⁽⁵⁾			±128	mA
	Continuous current through V_{CC} or GND			±100	mA
θ_{JA}	Package thermal impedance ⁽⁶⁾	DCK package		252	°C/W
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground, unless otherwise specified.

(3) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

(4) V_1 and V_0 are used to denote specific conditions for $V_{1/0}$.

(5) I_I and I_O are used to denote specific conditions for $I_{I/O}$.

(6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		2.3	3.6	V
V	Lick layer control input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	5.5	V
VIH	High-level control input voltage	$V_{CC} = 2.7 V \text{ to } 3.6 V$	2	5.5	v
V		V_{CC} = 2.3 V to 2.7 V	0	0.7	V
VIL	Low-level control input voltage	V_{CC} = 2.7 V to 3.6 V	0	0.8	
V _{I/O}	Data input/output voltage		0	5.5	V
T _A	Operating free-air temperature		-40	125	°C

 All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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ELECTRICAL CHARACTERISTICS⁽¹⁾

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIO	MIN	TYP ⁽²⁾	MAX	UNIT			
V _{IK}		$V_{CC} = 3 V, I_{I} = -18 mA$				-1.2	V		
V _{OH}		See Figure 3 and Figure 4							
I _{IN}	Control inputs	V_{CC} = 3.6 V, V_{IN} = 3.6 V to 5.5 V or GND			±10	μA			
	V _{CC} = 3.6 V,		$V_{I} = V_{CC} - 0.7 V \text{ to } 5.5 V$			±20			
II Swit		Switch ON,	$V_{I} = 0.7$ V to $V_{CC} - 0.7$ V			-40	μA		
		$V_{IN} = V_{CC}$ or GND	$V_1 = 0$ to 0.7 V			±5			
		V_{CC} = 3.6 V, V_{O} = 0 to 5.5 V, V_{I} = 0, Switch O			±10	μA			
I _{off}		$V_{CC} = 0, V_{O} = 0$ to 5.5 V, $V_{I} = 0$				10	μA		
I _{CC}		$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0,$	$V_{I} = V_{CC}$ or GND			20			
		Switch ON or OFF, $V_{IN} = V_{CC}$ or GND	V ₁ = 5.5 V			20	μA		
ΔI_{CC} ⁽⁴⁾	Control inputs	V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V,	Other inputs at V _{CC} or GND			300	μA		
C _{in}	Control inputs	V_{CC} = 3.3 V, V_{IN} = V_{CC} or GND			3		pF		
Cio(OFF)		V_{CC} = 3.3 V, $V_{I/O}$ = 5.5 V, 3.3 V, or GND, Swit	tch OFF, V _{IN} = V _{CC} or GND		5		pF		
		$V_{CC} = 3.3 \text{ V}$, Switch ON,	V _{I/O} = 5.5 V or 3.3 V		4				
C _{io(ON)}		$V_{IN} = V_{CC}$ or GND	$V_{I/O} = GND$		12		pF		
		$V_{CC} = 2.3 \text{ V}, \text{TYP} \text{ at } V_{CC} = 2.5 \text{ V},$	I _O = 24 mA		5	10			
		$V_{l} = 0$	I _O = 16 mA		5	10	Ω		
r _{on} ⁽⁵⁾			I _O = 24 mA		5	9			
		$V_{CC} = 3 V, V_I = 0$	I _O = 16 mA		5	9			

(1)

(2)

(3)

 V_{IN} and I_{IN} refer to control inputs. V_I , V_O , I_I , and I_O refer to data pins. All typical values are at $V_{CC} = 3.3$ V (unless otherwise noted), $T_A = 25^{\circ}$ C. For I/O ports, the parameter I_{OZ} includes the input leakage current. This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND. (4)

(5) Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

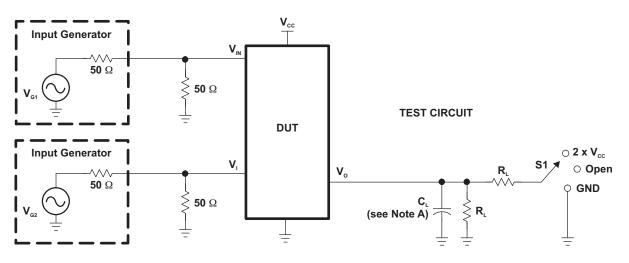
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 2 ± 0.2		V _{CC} = 3 ± 0.3	UNIT	
	(INPOT)	(001901)	MIN	MAX	MIN	MAX	
t _{en}	OE	A or B	1	10.5	1	9.5	ns
t _{dis}	OE	A or B	1	8.5	1	9	ns

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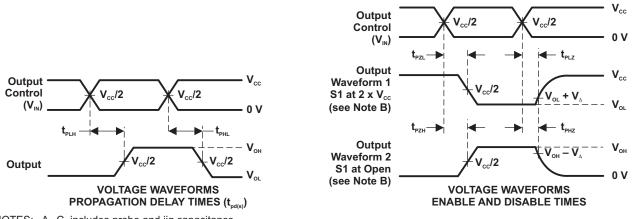


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PARAMETER MEASUREMENT INFORMATION



TEST	V _{cc}	S1	RL	V,	CL	V
t _{pd(s)}	$\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$	Open Open	500 Ω 500 Ω	3.6 V or GND 5.5 V or GND	30 pF 50 pF	
t _{PLZ} /t _{PZL}	$\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$	2 x V _{cc} 2 x V _{cc}	500 Ω 500 Ω	GND GND	30 pF 50 pF	0.15 V 0.15 V
t _{PHZ} /t _{PZH}	$\begin{array}{c} 2.5 \ V \pm 0.2 \ V \\ 3.3 \ V \pm 0.3 \ V \end{array}$	Open Open	500 Ω 500 Ω	3.6 V 5.5 V	30 pF 50 pF	0.15 V 0.15 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω, t_i ≤ 2.5 ns,
- 2. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_0 = 50 \Omega$, $t_i \leq 2$ $t_i \leq 2.5$ ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. $t_{\mbox{\tiny PLZ}}$ and $t_{\mbox{\tiny PHZ}}$ are the same as $t_{\mbox{\tiny dis}}.$
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. $t_{_{PLH}}$ and $t_{_{PHL}}$ are the same as $t_{_{pd(s)}}$. The tpd propagation delay is the calculated RC time constant of the typical ON-state

resistance of the switch nd the specified load capacitance, when driven by an ideal voltage source (zero output impedance). H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms

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TYPICAL CHARACTERISTICS

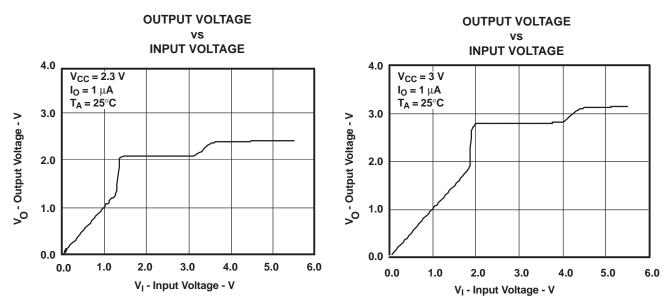


Figure 3. Data Output Voltage vs Data Input Voltage



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TYPICAL CHARACTERISTICS

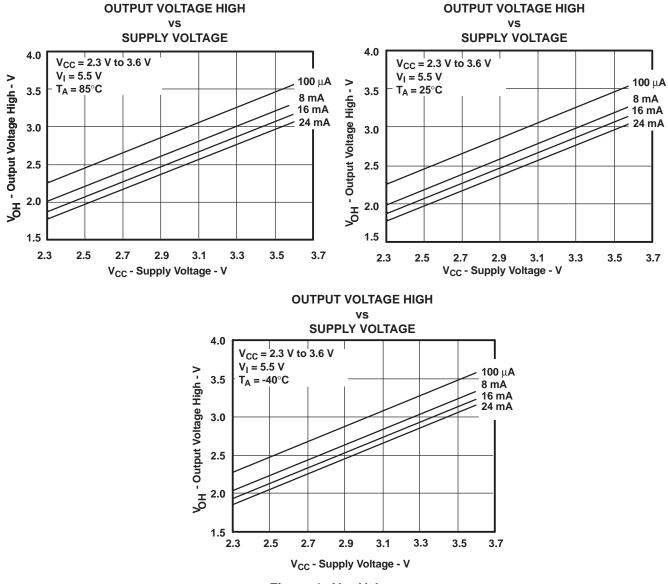


Figure 4. V_{OH} Values



10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	e Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
CCB3T1G125QDCKRQ1	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	72R	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN74CB3T1G125-Q1 :



PACKAGE OPTION ADDENDUM

10-Dec-2020

Catalog: SN74CB3T1G125

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CCB3T1G125QDCKRQ1	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

3-Aug-2017



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CCB3T1G125QDCKRQ1	SC70	DCK	5	3000	202.0	201.0	28.0

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



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